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2521/102	Candidate's Signature:	
2601/103		
2602/103	Date:	
2603/103	VA VA	60
ENGINEERING MATHEMATICS I		



THE KENYA NATIONAL EXAMINATIONS COUNCIL

DIPLOMA IN ELECTRICAL AND ELECTRONIC ENGINEERING (POWER OPTION) (TELECOMMUNICATION OPTION)

MODULE I

ENGINEERING MATHEMATICS

3 hours

(INSTRUMENTATION OPTION) astitute of Science JUL 2013

INSTRUCTIONS TO CANDIDATES

June/July 2015 Time: 3 hours

Write your name and index number in the spaces provided above.

Sign and write the date of the examination in the spaces provided above.

You should have Mathematical tables / Scientific calculator for this examination.

This paper consists of EIGHT questions.

Answer any FIVE questions in the spaces provided in this question paper.

All questions carry equal marks.

Maximum marks to each part of a question are as shown.

Do NOT remove any pages from this booklet.

Candidates should answer the questions in English.

For Examiner's Use Only

Question	. 1	2	3	4	5	6	7	8	TOTAL SCORE
Candidate's Score									

This paper consists of 20 printed pages.

Candidates should check the question paper to ascertain that all the pages are printed as indicated and that no questions are missing.

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Name:		Index No:	/
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2521/105, 2602/106 2601/106, 2603/106 ELECTRICAL MEASUREMENTS, AND ANALOGUE ELECTRONICS June/July 2015 Time: 3 hours



Candidate's Signature:	
Date:	

THE KENYA NATIONAL EXAMINATIONS COUNCIL

DIPLOMA IN ELECTRICAL AND ELECTRONIC ENGINEERING (POWER OPTION) (TELECOMMUNICATION OPTION) (INSTRUMENTATION OPTION) MODULE I

ELECTRICAL MEASUREMENTS AND ANALOGUE ELECTRONICS

3 hours

INSTRUCTIONS TO CANDIDATES

Write your name and index number in the spaces provided above.

Sign and write the date of the examination in the spaces provided above.

You should have Drawing instruments and Scientific calculator/mathematical table for this examination.

This paper consists of TWO sections; A and B.

Answer any THREE questions from section A and TWO questions from section B in the spaces provided in this question paper.

All questions carry equal marks.

Maximum marks for each part of a question are as shown.

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Candidates should answer the questions in English.

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Section	Question	Maximum Score	Candidate's Score
		20	
Λ		20	
2.%	5.0 458	20	
D		20	
В		20	
	Total Score	100	

This paper consists of 24 printed pages.

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(1) Junefuly 2015)

SECTION A

Answer any THREE questions from this section.

(a)	Explain the	following types	of errors whi	ich may occur	during measurement:
-----	-------------	-----------------	---------------	---------------	---------------------

- (i) gross errors;
- (ii) environmental errors;
- (iii) random errors.

(6 marks)

- (b) State any **two** factors that determine the choice of a suitable method of measuring resistance.
 - (ii) An unknown resistor in series with a milliammeter is measured using the ammeter-voltmeter method. The voltmeter used has a sensitivity of $1000~\Omega/v$ and reads 100~V on its 150~V scale when connected across the resistor. If the milliammeter reads 5~mA, determine the:
 - (I) apparent value of the resistor;
 - (II) actual value of the resistor;
 - (III) percentage error.

(8 marks)

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- (c) With the aid of a labelled diagram describe how a ballistic galvanometer is calibrated using Hibbert Magnetic standard. (6 marks)
- 2.\(\tau\) (a) (i) Define the following terms with respect to soldering:
 - (I) solder;
 - (II) flux.
 - (ii) Outline the procedure followed during soldering process.



- (b) (i) Distinguish between an integrated circuit (IC) and a printed circuit board (PCB).
 - (ii) Describe the following methods of fault location in electronic systems:
 - (I) functional area test;
 - (II) half-split.

(6 marks)

(c) (i) Explain the following types of maintenance in an electrical workshop. (I) corrective; (II)planned. (ii) Outline the steps involved in carrying out a planned maintenance programme. (8 marks) Explain the term "unit" in relation to measurements. (i) (ii) Differentiate between electrostatic system of units (ESU) and electromagnetic system of units (EMU). (6 marks) Explain the following standards of measurements: (b) astitute of Science LIBRARIAN (i) international; 3 1 JUL 2015 (ii) secondary. 110 00000 K (6 marks) (c) (i) Define the following in relation to errors and for each give its mathematical expression: (1) absolute; (II) relative. (ii) A standard measuring instrument measures the value of a resistance as 10.25Ω . If the actual value of the resistance is 10.22 Ω , determine the absolute error of measurement; (I) (II)percentage error. (8 marks) 4. . Define the following terms as applied in equipment reliability: (a) (i) Derating; Mean Time to Repair (MTTR) (ii) (4 marks) (b) (i) Explain the following with respect to equipment maintainability: availability; (I) life cycle costs. (II)

2015 (3)

- (ii) On the same axis of "users costs" Vs "availability" draw the graphs of :
 - (I) equipment price;
 - (II) costs of failure;
 - (III) total cost of I and II and determine optimum availability.

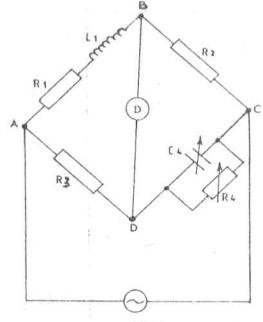
(9 marks)

- (c) (i) State any two categories of equipment manuals used to aid repair work.
 - (ii) Outline the main function of each of the following tools and measuring instruments when used in electronic laboratory.
 - (i) signal generator;
 - (ii) solder sucker;
 - (iii) long nose pliers;
 - (iv) screw driver;
 - (v) multimeter.

(7 marks)

- 5. (a) Distinguish between shunts and multipliers as applied in range extension of measuring instruments. (4 marks)
 - (b) With the aid of a labelled diagram describe the operation of a rectifier instrument when used for measurement of current. (6 marks)
 - (c) Figure 1 shows an a.c bridge used in the measurement of self inductance. At balance derive the expression for:
 - (i) industance, L₁;
 - (ii) Q factor for the circuit.

(10 marks)





Answer any TWO questions from this section.

6. (a) State any **two** charges found in an atom of an element.

(2 marks)

- (b) (i) Define "work function" in relation to electron emission.
 - (ii) Explain:
 - (I) how "space charge" is formed in a vacuum diode.
 - (II) the process of thermionic emission and give one application.

(6 marks)

- (c) With the aid of labelled energy band diagrams, explain the variation of the forbidden energy gap in the following materials.
 - (i) conductors;
 - (ii) insulators;
 - (iii) semi-conductors.

(12 marks)

- 7. (a) (i) State the two basic modes of operation of MOSFET.
 - (ii) Draw labelled N-channel symbol for each mode in a(i).

(3 marks)

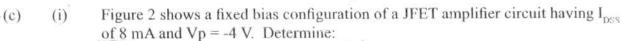
(b) With aid of labelled diagrams explain the principle of operation of an N-Channel Junction Field Effect Transistor (JFET) when biased from two sources.

(5 marks)

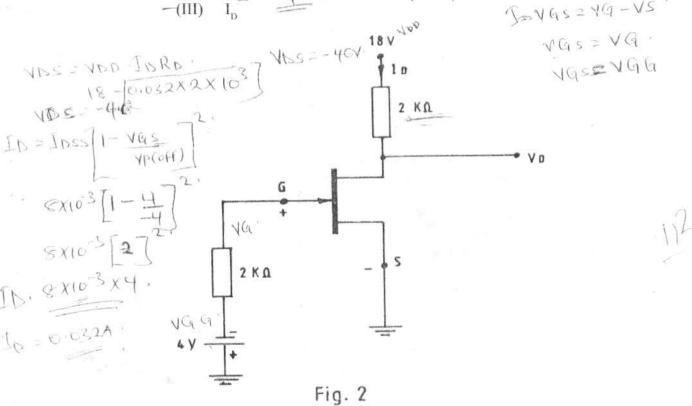


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(12 marks)



(I) V_D $V_{DS} = V_D = -\frac{46 \text{ M}}{1 - 1}$, $V_{QS} = V_{QQ}$



(ii) Figure 3 shows a common source self biased JFET amplifier with $I_{DSS} = 8$ mA, Vp = -6 V. The Q-point occurs at $I_{DQ} = 4$ mA. Assuming $R_D = 3R_S$, determine the value of resistor R_S and R_D .

RD
RD
RD
RD
RD
RS
RS

- A NPN transistor has $I_E = 10$ mA and dc current gain (α) of 0.967, determine (ii)

 - (II)
 - Ici = X=16 Ic = XIE Ic=IRIC.

 IB: 16/18

 B. J. J. C. X. J (III)

(9 marks)

Figure 4 shows a potential divider biased circuit. Assuming base-emitter voltage of (b) 0.5 V and $I_C \simeq I_F$, determine the:

- A IC = NBG collector current; Ic = (i)
 - (ii) collector-to-emitter voltage.

(8 marks)

oc.

VBC.

(c)

VBe ABG ON ADS Ie or 4 KA 1.5 K.A

C OV 10 . VCC = 22 V Re Jear ID Ic = Vcc-Vc 10 Kn Ye Re or RD Re.

VBC =

VCE = VCC - IdRetR

VCC-IR

Draw the de load line and mark the Q-point of the circuit in b(ii).

(3 marks)



VRe = -IOR

VGS OV VBE

19 = - ID

IDOIL

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Ic = Ic

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BIT & FET